

# Electronic Structure of Two-Dimensional Crystals of Hexagonal Boron Nitride

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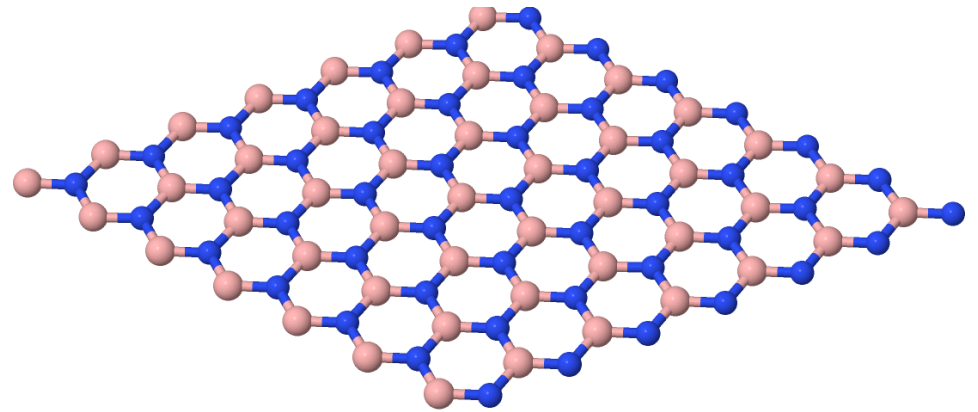
*QMC in the Apuan Alps VIII*

TTI, Tuscany, Italy

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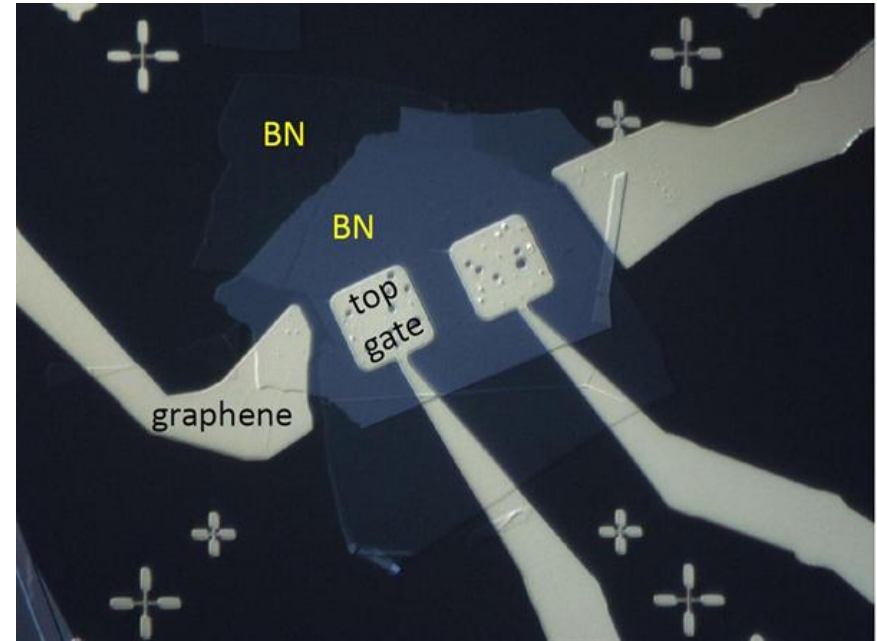
# Introduction: Hexagonal Boron Nitride (I)

- **H-BN**: B and N atoms occupy the *A* and *B* sublattices of a 2D honeycomb lattice.
  - Atomic structure and lattice parameter are similar to graphene.
  - However, whereas pristine graphene is a gapless semiconductor, **h-BN is an insulator** because the sublattice symmetry is broken.
- **Bulk h-BN (a.k.a. white graphite)**: BN layers are weakly bound together (mainly) by van der Waals interactions.
  - Gives rise to lubricating properties.
  - Possible to produce monolayers of BN by mechanical exfoliation.
- **Stacking arrangement of bulk h-BN**: *AA'*.  
Each  $B^{\delta+}$  ion has an  $N^{\delta-}$  vertically above it and *vice versa*.



## Introduction: Hexagonal Boron Nitride (II)

- H-BN is the best substrate for graphene-based electronics:
  - the surfaces may be **atomically smooth**;
  - it is a very **good insulator**; and
  - it has a **similar lattice parameter to graphene**.
- Atomically flat BN is also a potentially important component in novel electronic devices based on 2D materials, e.g., high-speed transistors and supercapacitors.
- To date, experimentalists have not succeeded in measuring the optoelectronic properties of monolayer BN. Our knowledge of these properties is based on:
  - extrapolation from experimental results for thin films (dozens of layers); and
  - density functional theory (DFT) calculations.



# Electronic Properties of Hexagonal Boron Nitride

- **Key optoelectronic property:** nature (direct or indirect) and magnitude of the **electronic band gap**.
- **Challenges for theory:**
  - Experimental results are currently unavailable.
  - DFT is not reliable for determining band gaps.
  - Bulk h-BN exhibits a large exciton binding energy. Estimates range from 0.149 eV (experiment plus Wannier model) to 0.72 eV (*GW*-Bethe–Salpeter equation). Exciton binding is enhanced in the monolayer.
  - **2D systems exhibit unpleasant finite-size effects.**
- We have therefore used **quantum Monte Carlo (QMC)** methods as implemented in CASINO to investigate the band structure and excitonic effects in h-BN.
  - We use variational Monte Carlo (VMC) and diffusion Monte Carlo (DMC).
  - First QMC calculations of the band structure of 2D materials?
- We have investigated the effects of **lattice dynamics** on the band gap within DFT.

# DFT Calculations (Relaxation, Lattice Dynamics, Band Structure)

- Parameters for our DFT (CASTEP) calculations:
  - Exchange-correlation functionals used: LDA, PBE and hybrid HSE06.
  - Artificial periodicity: 40 a.u.
  - $53 \times 53$   $\mathbf{k}$ -point grid in LDA and PBE band-structure calculations;  $29 \times 29$   $\mathbf{k}$ -point grid in lattice-dynamics calculations;  $11 \times 11$   $\mathbf{k}$ -point grid in HSE06 calculations
  - Plane-wave cutoff: 25 a.u. in calculations with ultrasoft pseudopotentials; 30 a.u. in (HSE06) calculations with norm-conserving pseudopotentials.
  - Finite displacements to evaluate force constants: 0.08 a.u.
- Replacing ultrasoft with norm-conserving pseudopotentials changed the DFT-PBE  $K \rightarrow \Gamma$  and  $K \rightarrow K$  gaps from 4.69 to 4.76 eV and 4.67 to 4.79 eV, respectively.
  - Uncertainty in gap due to pseudopotential:  $\sim 0.1$  eV. *Small, but makes the difference between predicting direct and indirect gaps.*
  - Dirac-Fock pseudopotentials used in our QMC calculations give similar DFT gaps to the norm-conserving pseudopotentials.
  - DFT-PBE lattice parameter changes from 2.512 to 2.487 Å when the ultrasoft pseudopotential is replaced by a norm-conserving pseudopotential.

# Nuclear Contribution to the Band Gap (I)

- **Born–Oppenheimer approximation**: electronic wave functions and energies depend parametrically on nuclear positions; electronic total energy acts as a potential in which the nuclei move.
  - When an electron is excited, the B.–O. potential surface abruptly changes.
  - Suppose we are at zero temperature, so all phonon modes are in their ground state.
  - **Nuclear contribution to total energy**: zero-point energy (ZPE) of phonon modes.
  - Provided the overlap between the ground-state nuclear wave functions in the electronic ground state and excited state is non-negligible, the phonon-renormalised gap is the difference between the total energy including phonon ZPE in the ground state and the total energy including ZPE in the electronic excited state.
- **To calculate the nuclear zero-point energy (ZPE) contribution to the band gap**:
  - *Perform DFT lattice dynamics calculation in the **electronic ground state**.*
  - *Perform DFT lattice dynamics calculation in the **electronic excited state**.*
  - *Difference in ZPEs gives nuclear correction to band gap at zero temperature.*

## Nuclear Contribution to the Band Gap (II)

- We used the method of finite displacements in a  $3 \times 3$  supercell and with an  $n \times n$   $\mathbf{k}$ -point grid in the supercell, including  $\Gamma$ .
- For the electronic excited state, we swapped the occupancies of the ground-state highest occupied and lowest unoccupied band.
- Taking the difference of the total ZPEs in the  $3n \times 3n$  supercell corresponding to the unfolded  $\mathbf{k}$  points gives the phonon contribution to the electronic excitation energy.
- The promotion of the electron from the highest occupied to the lowest unoccupied band at  $\Gamma$  in the  $3 \times 3$  supercell corresponds to a promotion at  $K$  in the Brillouin zone of the primitive cell; thus the phonon contribution to the gap calculated above is the correction to the  $K \rightarrow K$  gap.
- Assume the phonon corrections for  $K \rightarrow \Gamma$  are similar.
- The calculations used norm-conserving DFT pseudopotentials, the PBE exchange-correlation functional, a plane-wave cutoff energy of 40 a.u. and finite displacements of 0.08 a.u.

# Evaluating Quasiparticle and Excitonic Gaps in QMC (I)

- To calculate excitation energies using QMC: take **differences of total energies** obtained with trial wave functions that correspond to the ground state or an excited state.
  - Exploits the fixed-node approximation.
  - Choose orbital occupancy to get appropriate excited-state wave functions.
- **Quasiparticle bands for unoccupied states**:  $\mathcal{E}_i(\mathbf{k}) = E^+(\mathbf{k}, i) - E^{\text{GS}}$ , where  $E^+(\mathbf{k}, i)$  is the total energy when an electron is added to band  $i$  at  $\mathbf{k}$  and  $E^{\text{GS}}$  is the ground-state energy.
- **Quasiparticle bands for occupied states**:  $\mathcal{E}_i(\mathbf{k}) = E^{\text{GS}} - E^-(\mathbf{k}, i)$ , where  $E^-(\mathbf{k}, i)$  is the total energy when an electron is removed from band  $i$  at  $\mathbf{k}$ .
- **Quasiparticle band gap**: difference of the energy bands at conduction-band minimum (CBM) and valence-band maximum (VBM):

$$\Delta_{\text{qp}} = \mathcal{E}_{\text{CBM}} - \mathcal{E}_{\text{VBM}} = E_{\text{CBM}}^+ + E_{\text{VBM}}^- - 2E^{\text{GS}}.$$



## Evaluating Quasiparticle and Excitonic Gaps in QMC (II)

- **Excitonic gap**: energy difference when an electron is promoted from VBM to CBM:

$$\Delta_{\text{ex}} = E_{\text{VBM} \rightarrow \text{CBM}}^{\text{pr}} - E^{\text{GS}},$$

where  $E_{\text{VBM} \rightarrow \text{CBM}}^{\text{pr}}$  is the total energy evaluated with a trial wave function in which the VBM orbital has been replaced by the CBM.

- DMC retrieves a large but finite fraction of the correlation energy.
  - Hartree–Fock theory: band gaps are significantly overestimated.
  - Assume the fraction of correlation energy retrieved in the ground state is similar to the excited state: the DMC gaps are upper bounds.
  - If we increase the fraction of correlation energy retrieved, e.g., by including a backflow transformation, we expect to see a decrease in the energy gap.

## DMC for Excited States

- DMC for the lowest-energy eigenfunction that has the same symmetry as the trial wave function, provided that the trial wave function transforms as a 1D irreducible representation of the symmetry group of the Hamiltonian:
  - Variational principle for DMC energy: fixed-node error in energy is (i) positive and (ii) second order in the error in the nodal surface.
  - Zero-variance principle: if trial wave function is exact, all local energies are equal to the energy eigenvalue.
- DMC for a general excited state:
  - No variational principle: fixed-node error can be either positive or negative. Error is first order in the error in the nodal surface.
  - Energy expectation with a Slater(-Jastrow(-backflow)) trial wave function constructed using an appropriate set of orbitals will exceed the excited-state energy. Hence we expect the fixed-node error will be positive in general.
  - Still have zero-variance principle.
- So DMC “works” for excited states.

# Trial Wave Functions, Etc. (I)

- We used Slater-Jastrow (SJ) wave functions:
  - DFT-PBE orbitals from CASTEP were re-represented in **blips** (i) to improve the scaling and (ii) to discard the artificial periodicity in the out-of-plane direction.
  - **Jastrow factor**: electron–electron (isotropic polynomial plus 2D plane wave expansion), electron–ion and electron–electron–ion terms were optimised by **unweighted variance minimisation**.
  - **Bitter experience**: wave functions optimised by unweighted variance minimisation are less likely to result in population explosions in DMC than wave functions optimised by energy minimisation.
- All DMC gaps have been linearly extrapolated to zero time step (using time steps of 0.01 and 0.04 a.u.).
- We used the ground-state Jastrow factor (and backflow function) in excited states.
  - Fixed-node DMC energy does not depend on the Jastrow factor.
  - Relaxation of backflow in an excited state is a manifestation of finite-size error.

## Trial Wave Functions, Etc. (II)

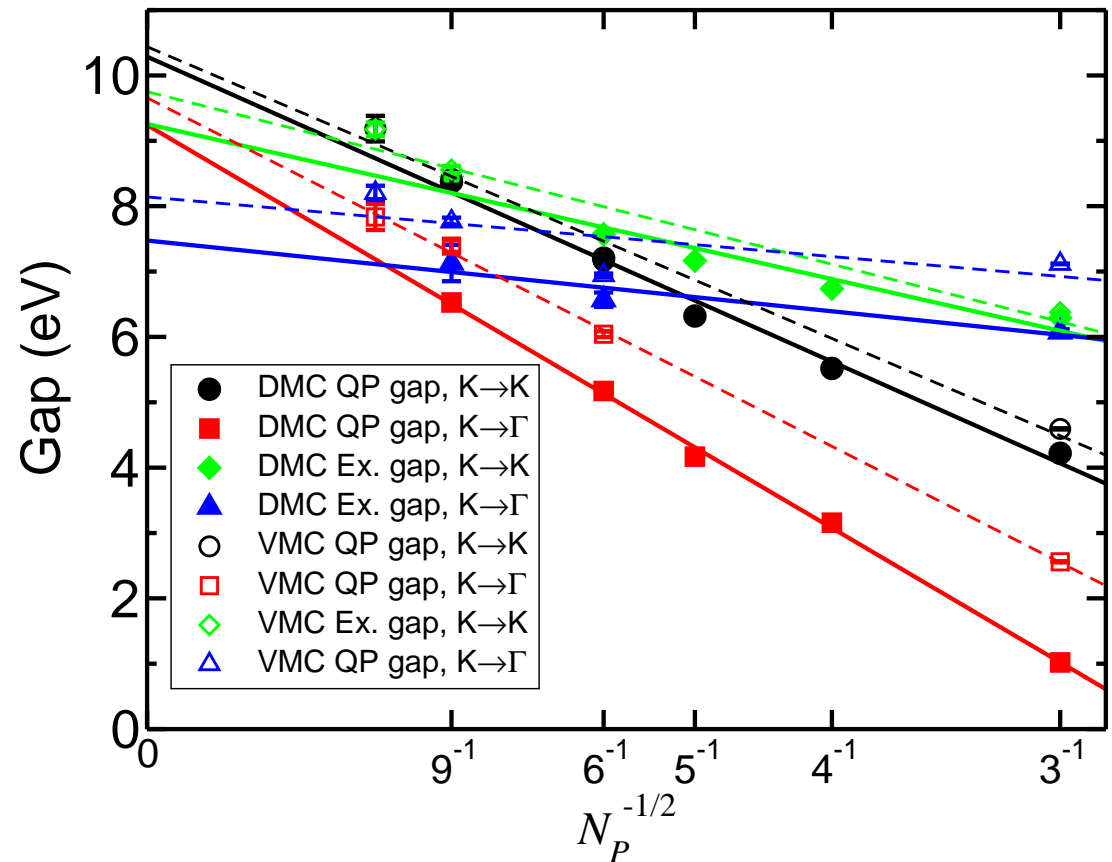
- We performed test calculations with Slater-Jastrow-backflow wave functions:
  - SJB wave functions were optimised by energy minimisation.
  - Backflow reduces the DMC gaps by a small amount [0.10(3) eV on average].
  - VMC and DMC results in a  $3 \times 3$  cell:

Method	$E^{\text{GS}}$ (eV/p. cell)	$\sigma_{\text{GS}}^2$ (a.u.)	QP gap (eV)		Exc. gap (eV)	
			$K \rightarrow \Gamma$	$K \rightarrow K$	$K \rightarrow \Gamma$	$K \rightarrow K$
HFVMC	-341.961(4)	21.39	2.63(8)	5.95(8)	7.13(5)	7.65(5)
SJ-VMC	-349.8780(4)	3.18	2.559(9)	4.593(9)	7.118(6)	6.378(5)
SJB-VMC	-350.229(2)	2.11	2.55(4)	4.46(4)	7.18(2)	6.30(2)
SJ-DMC	-350.747(4)	N/A	1.02(9)	4.22(8)	6.08(4)	6.29(4)
SJB-DMC	-350.857(2)	N/A	0.86(4)	4.09(4)	6.04(2)	6.22(2)

- The fraction of SJB-DMC correlation energy retrieved at the SJ-VMC or SJB-VMC level is much smaller for excited states than the ground state.
  - Undermines our assumption that the quality of our calculations is similar in the ground state and excited state.

## Comparison of VMC and DMC Gap Results

- VMC is cheaper than DMC, by a factor of more than 50.
- Whereas fixed-node DMC total energies (and hence gaps) are independent of the Jastrow factor, this is not true of VMC.
- Nevertheless, any effect of not reoptimising the Jastrow factor in excited states is a form of finite-size error.



- The VMC gaps are generally larger than the DMC gaps, as expected.
- Although the VMC and DMC gaps show the same finite-size behaviour, the VMC results cannot be used to extrapolate the DMC gaps to the thermodynamic limit, even though VMC results can be obtained for substantially larger system sizes.

# Singlet and Triplet Excitonic States

- We have calculated the SJ-DMC energy differences between the **singlet** and **triplet** excitonic states in  $3 \times 3$  supercells of BN.
- We used single-determinant trial wave functions in which an electron was promoted without and with a spin-flip.
- We used the set of orbitals obtained in a non-spin-polarised ground-state DFT-PBE calculation together with the Jastrow factor optimised in the ground state.
- The singlet excitonic state for a promotion from  $K \rightarrow K$  is 0.12(2) eV lower in energy than the triplet state.
- For  $K \rightarrow \Gamma$ , the triplet excitonic state is lower in energy by 0.02(2) eV (insignificant).
- Apart from these tests, all the calculations reported in this article were performed using singlet excitonic states.

## Finite-Size Effects (I)

- Although the asymptotic behaviour of the ground-state energy as a function of system size in a 2D-periodic system is known, the asymptotic form of the finite-size error in the band gaps is unknown.
- We used a range of simulation cell sizes, from  $2 \times 2$  to  $9 \times 9$  primitive cells.
- Different choices of simulation-cell Bloch vector  $\mathbf{k}_s$  allow one to obtain different points on the band structure in a finite cell:
  - For a  $3n \times 3n$  supercell with  $\mathbf{k}_s = \mathbf{0}$ , the orbitals include bands at both  $\Gamma$  and  $K$ . One can make additions or subtractions at  $\Gamma$  or  $K$  and promote electrons either from  $K$  to  $\Gamma$  or from  $K$  to  $K$ .
  - Otherwise, one can choose  $\mathbf{k}_s$  so that the orbitals at  $\Gamma$  are present, or the orbitals at  $K$ , but not both.
  - Hence it is only possible to calculate the  $K \rightarrow \Gamma$  excitonic gap in  $3n \times 3n$  supercells.
  - The quasiparticle gap from  $K \rightarrow \Gamma$  can always be calculated for a given supercell size by determining the CBM and VBM using two different values of  $\mathbf{k}_s$ .

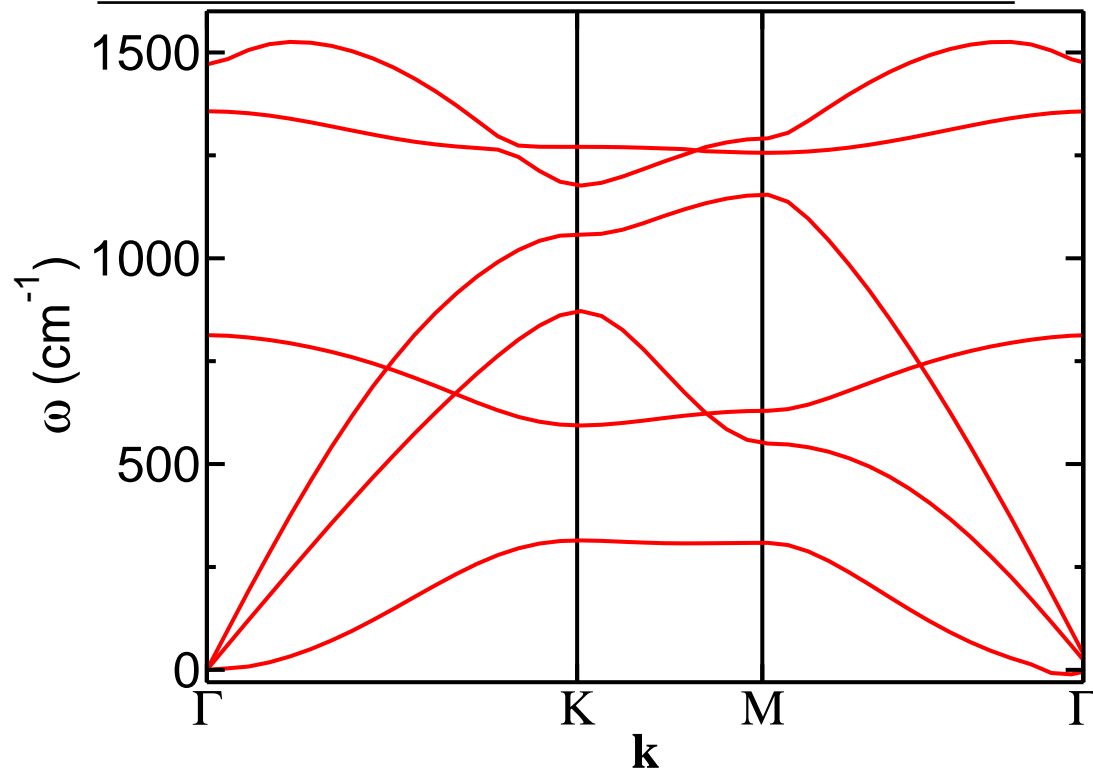
## Finite-Size Effects (II)

- In these preliminary results we have **assumed** the finite-size error is inversely proportional to the linear size of the cell.
  - This is a plausible finite-size scaling that is not obviously inconsistent with the results shown in the figure.
  - **To-do**: work out what the scaling ought to be. **Answers on a postcard, please.**
- It is likely that the excitonic gap will behave differently as a function of system size once the linear size of the simulation cell exceeds the **exciton Bohr diameter**.
  - When the simulation cell is small, the exciton is artificially compressed, leading to an overestimate of the binding energy.



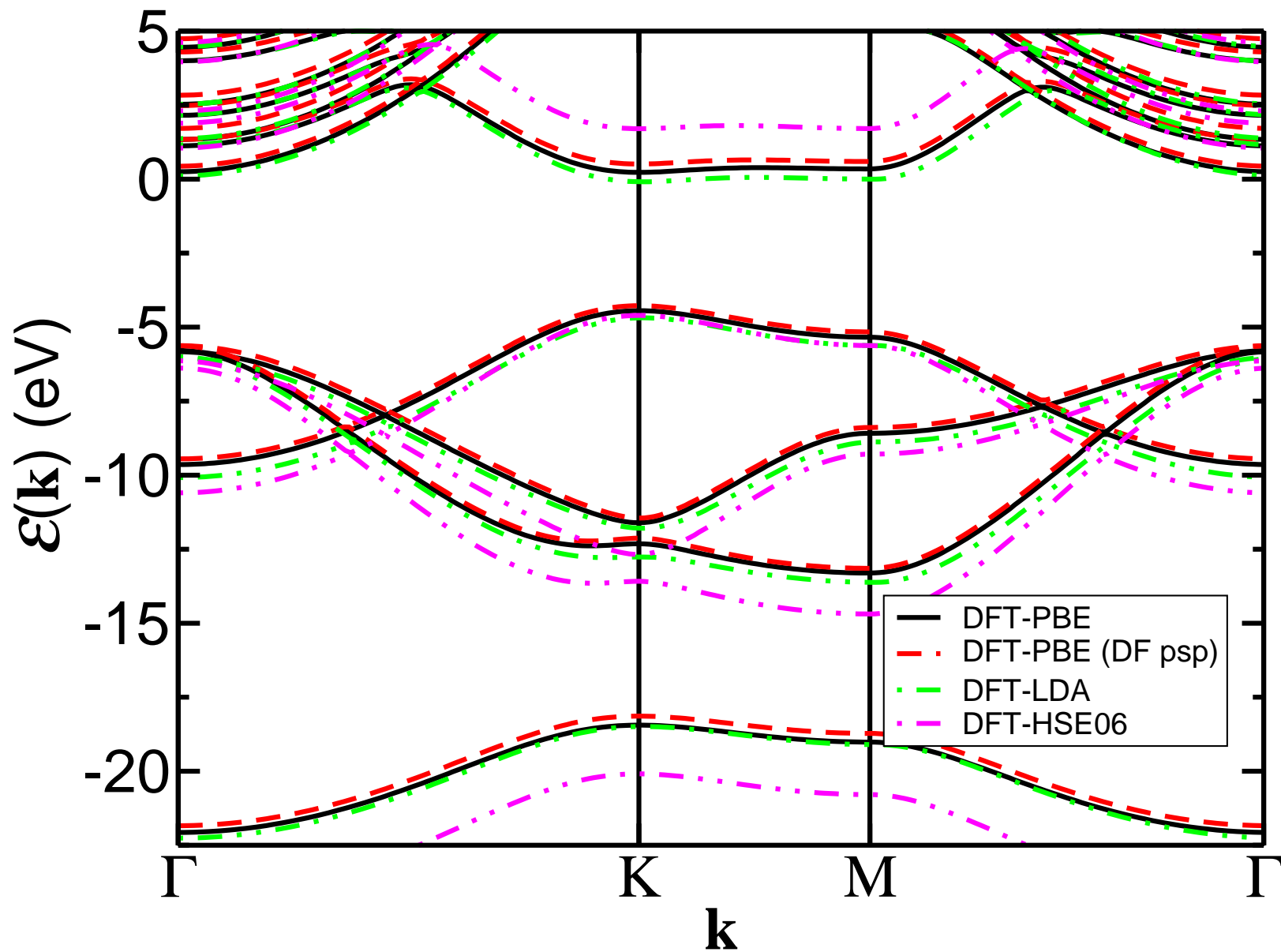
## Results: Lattice Parameter and Dynamical Stability (I)

Method	Lattice parameter (Å)
DFT-LDA	2.491
DFT-PBE	2.512
DFT-HSE06	2.45
Exp. (bulk)	2.5040



- We used the DFT-PBE lattice parameter in all our QMC calculations.
- Phonon dispersion curve was obtained using DFPT.
  - LO branch ought to go linearly to TO frequency at  $\Gamma$ ; the fact that it does not is due to the artificial periodicity.
- There is a small (spurious) region of dynamical instability at  $\Gamma$ , which depends on plane-wave cutoff,  $\mathbf{k}$ -point sampling, etc.

## Results: DFT Band Structures



## Results: Band Effective Masses (I)

- We fitted

$$\mathcal{E}(\mathbf{k}) = \mathcal{E}_0 \pm \frac{k^2}{2m} + Ak^4 + Bk^6 + Ck^6 \cos(6\theta) + Dk^3 \cos(3\theta) + Ek^5 \cos(3\theta),$$

to the valence and conduction bands within a circle of radius 10% of the  $\Gamma$ - $M$  distance around the  $K$  point, where  $\mathbf{k}$  is the wavevector relative to the  $K$  point.

– The root-mean-square residual over this area is less than 0.3 meV in each case.

- We fitted

$$\mathcal{E}(\mathbf{k}) = \mathcal{E}_0 \pm \frac{k^2}{2m} + Ak^4 + Bk^6 + Ck^6 \cos(6\theta),$$

to the conduction band within a circle of radius 40% of the  $\Gamma$ - $M$  distance about  $\Gamma$ .

– RMS residual over this area is less than 0.3 meV.

– It is clearly much easier to represent the band over a large area around  $\Gamma$  than  $K$ .

- The band edge and effective mass are unchanged when the radius of the region used for the fit is reduced.

## Results: Band Effective Masses (II)

Method	Band	Location	$\mathcal{E}_0$	$m$
DFT-LDA	Cond.	$\Gamma$	0.00397	0.96
DFT-LDA	Cond.	$K$	-0.00327	0.89
DFT-LDA	Val.	$K$	-0.172	0.61
DFT-PBE	Cond.	$\Gamma$	0.00919	0.95
DFT-PBE	Cond.	$K$	0.00838	0.90
DFT-PBE	Val.	$K$	-0.163	0.63
DFT-HSE06	Cond.	$\Gamma$	0.0471	0.98
DFT-HSE06	Cond.	$K$	0.0711	1.07
DFT-HSE06	Val.	$K$	-0.161	0.63

# Mott–Wannier Model of Excitonic Effects

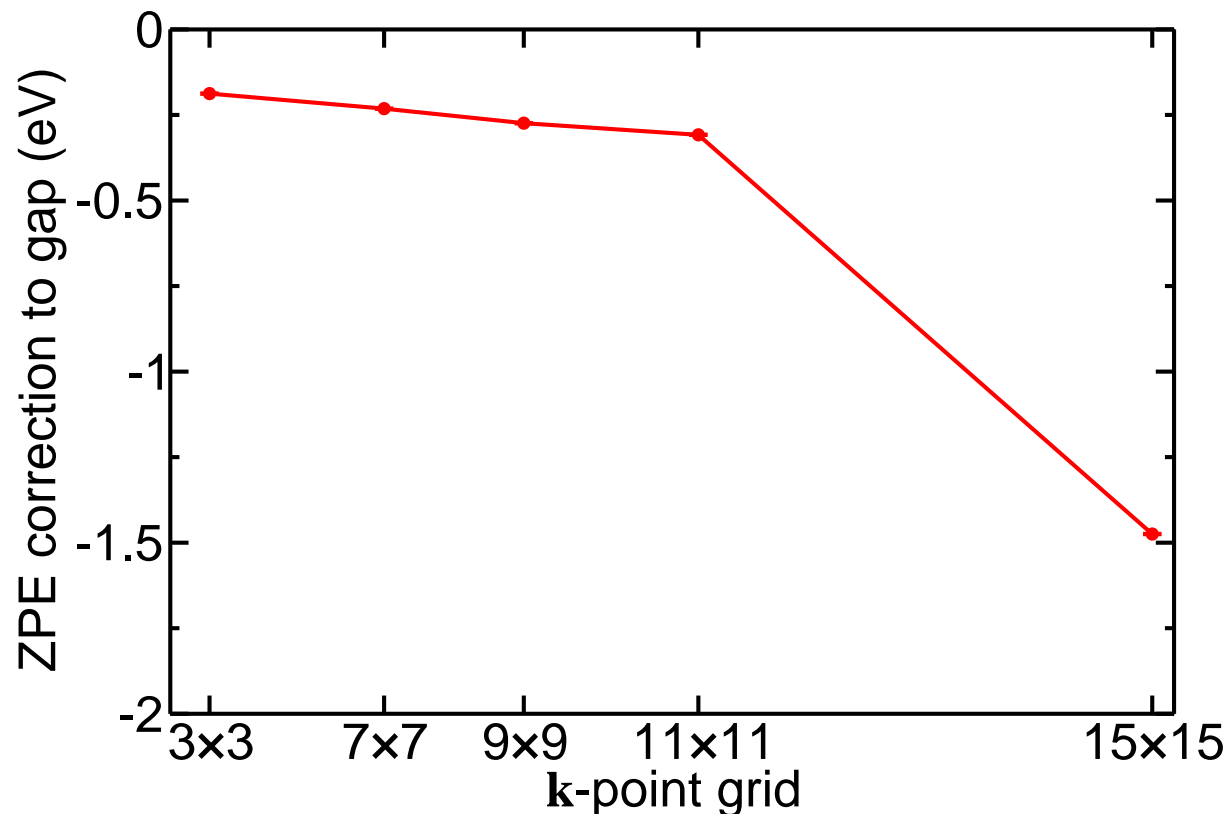
- Mott–Wannier binding energy of an exciton in 2D:  $E_{\text{ex}} = -2\mu/\epsilon^2$ , where  $\mu = m_e m_h / (m_e + m_h)$  is the exciton reduced mass and  $m_e$  and  $m_h$  are the electron and hole masses, respectively.
- Corresponding exciton Bohr radius:  $a_{\text{ex}} = \epsilon/\mu$ .
- Experimental static in-plane dielectric constant of bulk h-BN:  $\epsilon = 6.85$ . Assume the dielectric constant for monolayer BN to be similar.

Method	Excitation	Bohr rad. (Å)	Bind. en. (eV)
DFT-LDA	$K \rightarrow \Gamma$	9.74	-0.433
DFT-LDA	$K \rightarrow K$	10.0	-0.420
DFT-PBE	$K \rightarrow \Gamma$	9.58	-0.439
DFT-PBE	$K \rightarrow K$	9.79	-0.430
DFT-HSE06	$K \rightarrow \Gamma$	9.47	-0.445
DFT-HSE06	$K \rightarrow K$	9.15	-0.460

- Wigner–Seitz cell radius of largest supercell used ( $9 \times 9$ ): 9.26 Å.

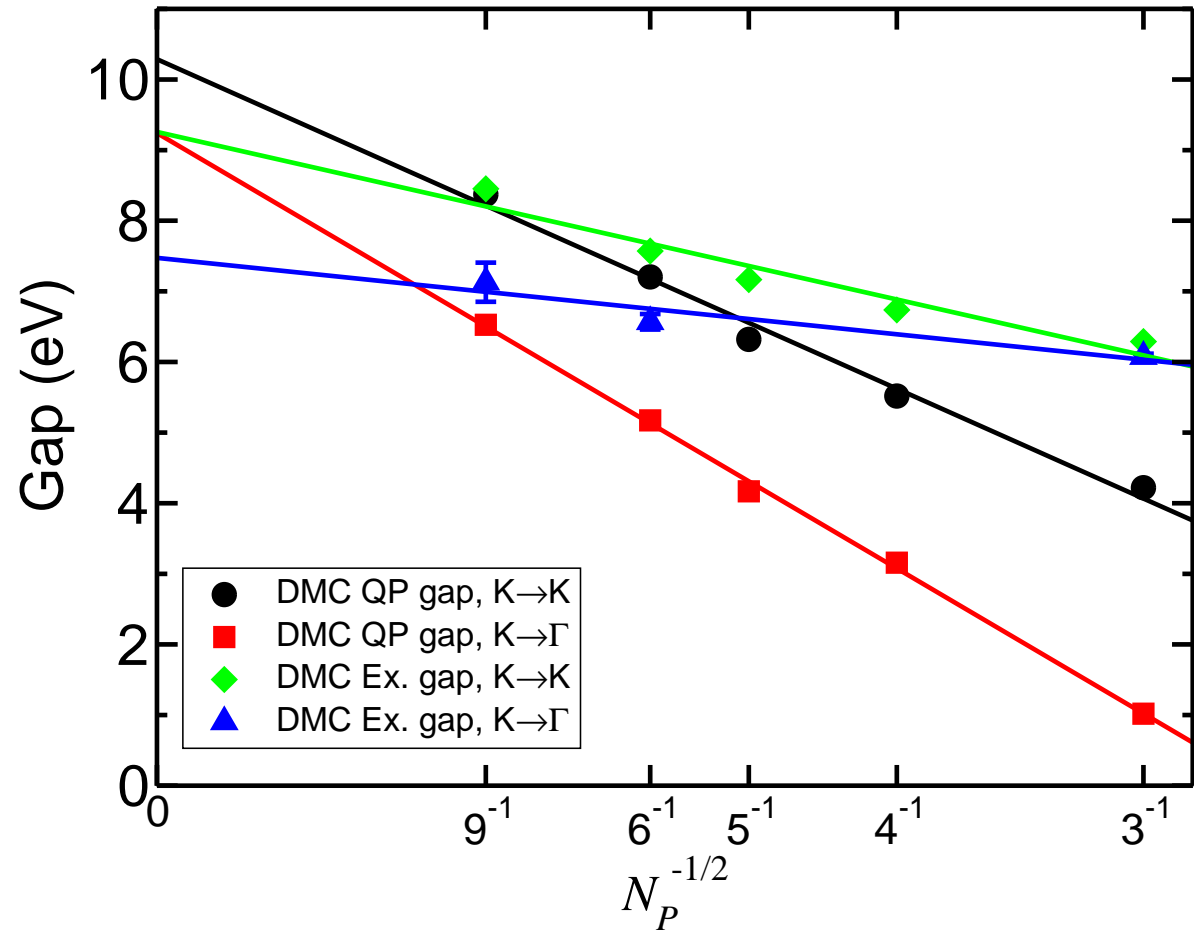
# Renormalisation of the Gap due to Electron–Phonon Coupling

- Nuclear motion causes a small but significant reduction in the electronic band gap.
  - The gap renormalisation shows great sensitivity to the number of  $\mathbf{k}$  points used in the  $3 \times 3$  supercell. No real evidence of convergence.
  - Perhaps of the order  $-0.3$  eV.
  - To-do: use the approach described by Bartomeu. Ought to agree. . .



## Finite-Size Effects

- Finite-size extrapolation with guess at exponent. . .
- Excitons are unbound in small cells.
  - They are bound in the infinite system limit (as one would rather hope).
  - They become bound once the cell size becomes comparable with the estimated exciton Bohr diameter.



## Energy-Gap Results

- We find the gap of monolayer BN to be **indirect** ( $K \rightarrow \Gamma$ ) and about 7.2 eV.
- **Experiment for single-crystal h-BN with around 15 layers:** find a direct ( $K \rightarrow K$ ) gap of 5.9 eV in single-crystal BN with around 15 layers.

Method	Quasiparticle gap (eV)		Excitonic gap (eV)	
	$K \rightarrow \Gamma$	$K \rightarrow K$	$K \rightarrow \Gamma$	$K \rightarrow K$
DFT-LDA	4.79	4.60	N/A	N/A
DFT-PBE	4.69	4.67	N/A	N/A
DFT-HSE06	5.65	6.31	N/A	N/A
<i>GW</i>	7.00	7.70	N/A	N/A
DMC	9.5(1)	10.4(2)	7.5(3)	8.7(3)

- In the thermodynamic limit the excitonic gaps lie below the quasiparticle gaps, as expected.
- **The exciton binding is large:** 1.7(4) eV for  $K \rightarrow K$  and 2.0(3) eV for  $K \rightarrow \Gamma$ .



## Conclusions

- We have performed DFT and QMC calculations to determine the electronic structure of monolayers of hexagonal BN, as an example of a 2D material.
- We find the QP gap to be indirect ( $K \rightarrow \Gamma$ ) and of magnitude 9.5 eV.
- We find that monolayer BN exhibits a very large exciton binding energy of about 2 eV.
- Not much agreement between DFT,  $GW$  or QMC.

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